## **NCE Automotive N-Channel Super Trench Power MOSFET**

### **Description**

The NCEAP60T12AD uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

### **General Features**

• V<sub>DS</sub> =60V,I<sub>D</sub> =150A

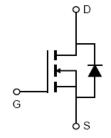
 $R_{\text{DS(ON)}} < 4.3 \text{m}\Omega \ \textcircled{0} \ \text{V}_{\text{GS}} \text{=} 10 \text{V} \quad \text{(Typ:} 3.5 \text{m}\Omega\text{)}$ 

 $R_{DS(ON)} < 5.3 \text{m}\Omega$  @  $V_{GS} = 4.5 \text{V}$  (Typ:4.0 m $\Omega$ )

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified







**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP60T12AD	NCEAP60T12AD	TO-263-2L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vos	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	150	А
Diam Current-Continuous	I <sub>D</sub> (100℃)	VDS 60   VGS ±20   ID 150	Α
Pulsed Drain Current	I <sub>DM</sub>	480	Α
Maximum Power Dissipation	P <sub>D</sub>	180	W
Derating factor		1.2	W/°C
Single pulse avalanche energy (Note 2)	E <sub>AS</sub>	500	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case	Rejc	0.83	°C/W

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# NCEAP60T12AD

## Electrical Characteristics (Tc=25°C unless otherwise noted)

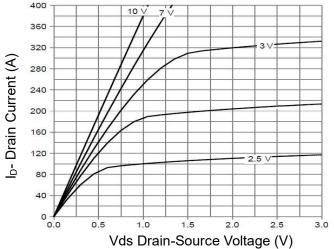
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			<u>.</u>			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.7	2.4	V
Drain-Source On-State Resistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.5	4.3	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	4.0	5.3	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =20A	40	-	-	S
Dynamic Characteristics						
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V,	-	4000	-	pF
Output Capacitance	Coss		-	680	-	pF
Reverse Transfer Capacitance	Crss	F-1.UIVIDZ	-	23	-	pF
Switching Characteristics (Note 1)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	11	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30 $V$ , $I_D$ =20 $A$	-	5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =4.7 $\Omega$	-	56	-	nS
Turn-Off Fall Time	t <sub>f</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA V <sub>GS</sub> =10V, I <sub>D</sub> =20A V <sub>DS</sub> =4.5V, I <sub>D</sub> =20A V <sub>DS</sub> =10V,I <sub>D</sub> =20A V <sub>DS</sub> =30V,V <sub>GS</sub> =0V, F=1.0MHz	-	12	-	nS
Total Gate Charge	Qg	V 20VI 20A	-	67	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	12	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	8.5	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	150	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	48	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	60	-	nC

### Notes:

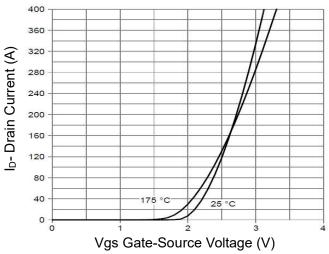
- 1. Defined by design.Not Subject to production test
- 2. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.







**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

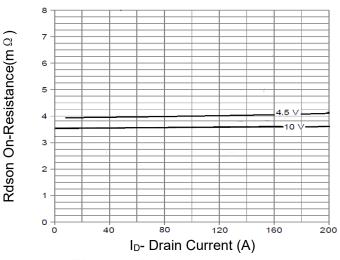


Figure 3 Rdson- Drain Current

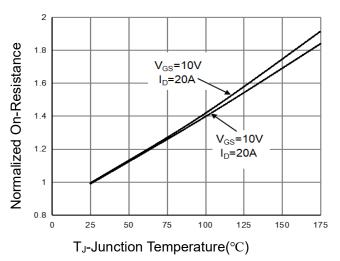


Figure 4 Rdson-JunctionTemperature

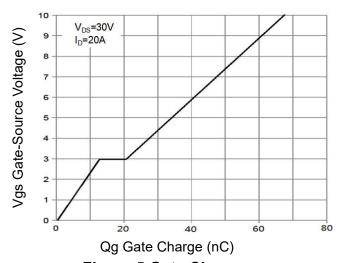


Figure 5 Gate Charge

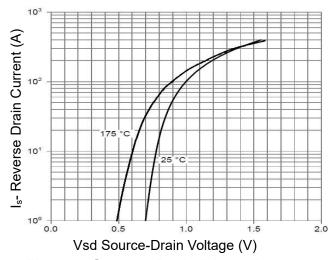


Figure 6 Source- Drain Diode Forw



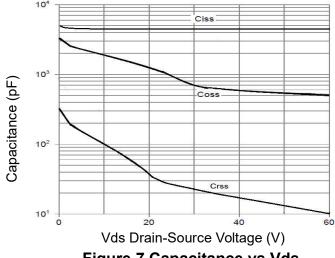


Figure 7 Capacitance vs Vds

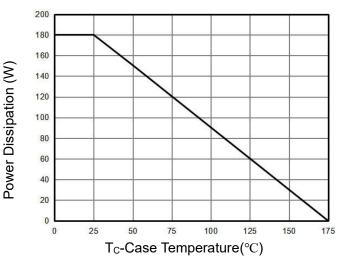


Figure 9 Power De-rating

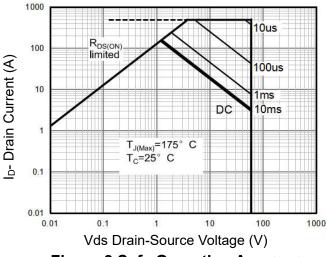


Figure 8 Safe Operation Area (Note 3)

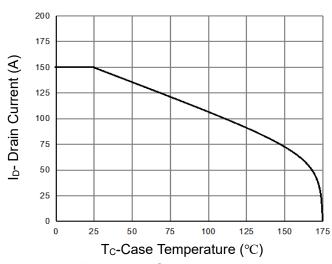
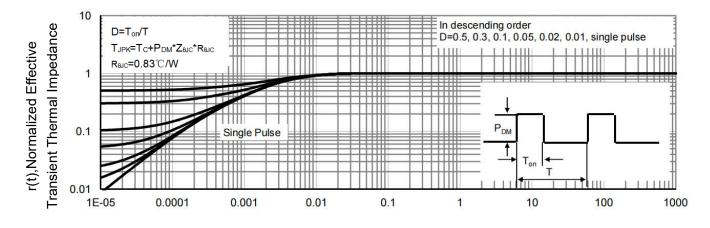


Figure 10 Current De-rating

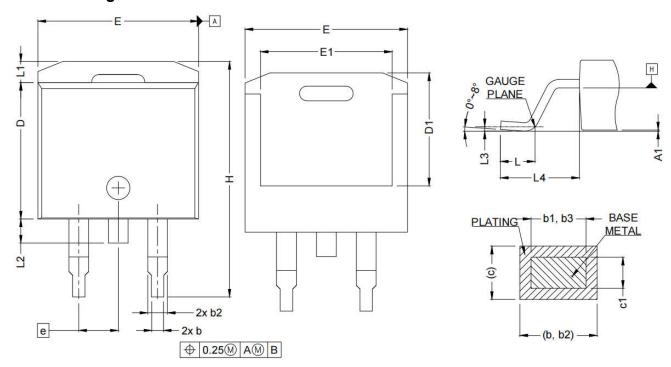


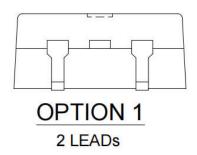
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



## **TO-263-2L Package Information**





SYMBOL	MIN.	MAX.	SYMBOL	MIN.	MAX.
A	4.36	4.56	Е	10.15	10.55
A1	0	0.25	E1	8.10	8.70
b	0.70	0.90	e	2.54	BSC
b1	0.51	0.89	Н	15.00	15.60
b2	1.17	1.37	L	1.90	2.50
b3	1.17	1.37	L1		1.65
С	0.38	0.69	L2		1.78
c1	0.38	0.53	L3	0.25	ГҮР
c2	1.19	1.34	L4	4.78	5.28
D	8.60	9.00	J1	2.56	2.96
D1	6.90	7.50			



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## NCEAP60T12AD

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